Advanced Monolithic Systems

AMSOP-77

ULTRA LOW OFFSET VOLTAGE OPERATIONAL AMPLIFIER

RoHS compliant

FEATURES

- **Outstanding Linearity**
- **Low V_{OS} overTemperature……. 55µV Max**
- **Excellent V_{OS} Drift……. 0.6µV/°C Max**
- **Ultra High Gain…….5000V/mV Min**
- **High PSRR……3µV/V Max**
- **Low Power Consumption…….60mW Max**

APPLICATIONS

- **High-Gain Instrumentation**
- **Precision Data Acquisition**
- **Precision Integrators**
- **Precision Threshold Detectors**
- **Biomedical Amplifiers**

GENERAL DESCRIPTION

The AMSOP-77 is a precision operational amplifier with an ultra low input offset voltage. This device features a wide input voltage range of ±13V minimum, low input bias current, high impedance, high PSRR, high CMRR, excellent stability of offsets and gain over time and temperature. Exceptional gain linearity eliminates incorrectable system nonlinearities common in previous monolithic op amps, and provides superior performance in high closed-loop gain applications.
Low cost, low noise, low offsets and high open-loop gain make the AMSOP-77 an excellent choice particularly for high-gain instrumentation applications. Other applications include precision data acquisition, precision integrators, threshold detectors and medical instrumentation.

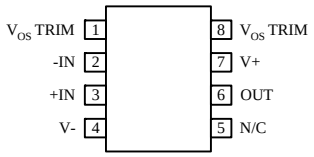
The AMSOP-77 is operational in the commercial temperature range of 0°C to 70°C and is available in the 8 lead SOIC and plastic dip (PDIP) packages.

ORDERING INFORMATION:

TOL.	PACKAGE TYPE		OPERATING TEMPERATURE RANGE
	8 LEAD SOIC	8 LEAD PDIP	
±25µV	AMSOP-77ES	AMSOP-77EP	0 to 70° C
±60µV	AMSOP-77FS	AMSOP-77FP	0 to 70° C
±100µV	AMSOP-77GS	AMSOP-77GP	0 to 70° C

PIN CONNECTIONS

8 Lead SOIC/ 8Lead PDIP



Top View

ABSOLUTE MAXIMUM RATINGS (Note1)

Supply Voltage	±22V	Storage temperature	-65°C to +125°C
Differential Input Voltage	±30V	Junction Temperature	+150°C
Input Voltage	±22V	Soldering information (25 sec)	265°C
Output Short Circuit Duration	Indefinite	Thermal Resistance	
Operating Temperature Range	0°C to70°C	8 L SOIC	158°C/W
		8 L PDIP	103°C/W

ELECTRICAL CHARACTERISTICS

Electrical Characteristics at V_{IN} =±15V and T_A = +25°C unless otherwise specified.

Parameter	Conditions	AMSOP-77E			AMSOP-77F			AMSOP-77G			Units
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage			10	25		20	60		50	100	µV
Long Term V_{OS} Stability	(Note 2)		0.3			0.4			0.4		µV/Mo
Input Offset Current			0.3	1.5		0.3	2.8		0.3	2.8	nA
Input Bias Current		-0.2	1.2	2.0	-0.2	1.2	2.8	-0.2	1.2	2.8	nA
Input Noise Voltage	0.1Hz to 10Hz		0.35	0.6		0.38	0.65		0.38	0.65	μV_{P-P}
Input Noise Voltage Density	f_O = 10Hz f_O = 100Hz (Note 3) f_O = 1000Hz		10.3 10.0 9.6	18.0 13.0 11.0		10.5 10.2 9.8	20.0 13.5 11.5		10.5 10.3 9.8	20.0 13.5 11.5	nV/√Hz
Input Noise Current	0.1Hz to 10Hz		14	30		15	35		15	35	pA_{P-P}
Input Noise Current Density	f_O = 10Hz f_O = 100Hz (Note 3) f_O = 1000Hz		0.32 0.14 0.12	0.80 0.23 0.17		0.35 0.15 0.13	0.90 0.27 0.18		0.35 0.15 0.13	0.90 0.27 0.18	pA/√Hz
Input Resistance Differential-Mode	(Note 4)	26	45		18.5	45		18.5	45		MΩ
Input Resistance Common-Mode			200			200			200		GΩ
Input Voltage Range		± 13	± 14		± 13	± 14		± 13	± 14		V
Common-Mode Rejection Ratio	V_{CM} = ± 13		0.1	1.0		0.1	1.6		0.1	1.6	µV/V
Power Supply Rejection Ratio	V_S = ± 13 to ± 18		0.7	3.0		0.7	3.0		0.7	3.0	µV/V
Large-Signal Voltage Gain	R_L≥2kΩ, V_O =± 10V	5000	12000		2000	6000		2000	6000		V/mV
Output Voltage Swing	R_L ≥10kΩ R_L ≥2kΩ R_L ≥1kΩ	± 13.5 ± 12.5 ± 12.0	± 14.0 ± 13.0 ± 12.5		± 13.5 ± 12.5 ± 12.0	± 14.0 ± 13.0 ± 12.5		± 13.5 ± 12.5 ± 12.0	± 14.0 ± 13.0 ± 12.5		V
Slew Rate	R_L ≥2kΩ (Note 3)	0.1	0.3		0.1	0.3		0.1	0.3		V/µs
Closed-Loop Bandwidth	A_{VCL} =+1 (Note 3)	0.4	0.6		0.4	0.6		0.4	0.6		MHz
Open-Loop Output Resistance	V_O = 0, I_O= 0		60			60			60		Ω
Power Consumption	V_S =± 15V, No Load V_S =± 3V, No Load		50 3.5	60 4.5		50 3.5	60 4.5		50 3.5	60 4.5	mW
Offset Adjustment Range	R_P =20kΩ		± 3			± 3			± 3		mV

ELECTRICAL CHARACTERISTICS

Electrical Characteristics at V_{IN}= ±15, 0°C ≤ T_A ≤ +70°C unless otherwise specified.

Parameter	Conditions	AMSOP-77E			AMSOP-77F			AMSOP-77G			Units
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage			10	55		20	100		80	150	µV
Average Input Offset Voltage Drift	(Note 3)		0.3	0.6		0.4	1.0		0.7	1.2	µV/°C
Input Offset Current			0.5	2.2		0.5	4.5		0.5	4.5	nA
Average Input Offset Current Drift	(Note 5)		1.5	40		1.5	85		1.5	85	pA/°C
Input Bias Current		-0.2	2.4	4.0	-0.2	2.4	6.0	-0.2	2.4	6.0	nA
Average Input Bias Current Drift	(Note 5)		8	40		15	60		15	60	pA/°C
Input Voltage Range		± 13.0	± 13.5		± 13.0	± 13.5		± 13.0	± 13.5		V
Common-Mode Rejection Ratio	V_{CM} = ± 13		0.1	1.0		0.1	3.0		0.1	3.0	µV/V
Power Supply Rejection Ratio	V_S = ± 13 to ± 18		1.0	3.0		1.0	5.0		1.0	5.0	µV/V
Large-Signal Voltage Gain	R_L≥2kΩ, V_O =± 10V	2000	6000		1000	4000		1000	4000		V/mV
Output Voltage Swing	R_L ≥2kΩ	± 12.0	± 13.0		± 12.0	± 13.0		± 12.0	± 13.0		V
Power Consumption	V_S = ± 15V, No Load		60	75		60	75		60	75	mW

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

Note 2: Long-Term Input Offset Voltage Stability refers to the averaged trend line of VOS vs. Time over extended periods after the first 30 days of operation. Excluding the initial hour of operation, changes in V_{OS} during the first 30 operating days are typically 2.5µV. Parameter is sample tested.

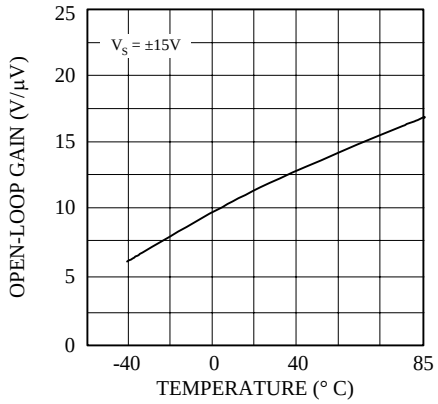
Note 3: Sample tested

Note 4: Guaranteed by design.

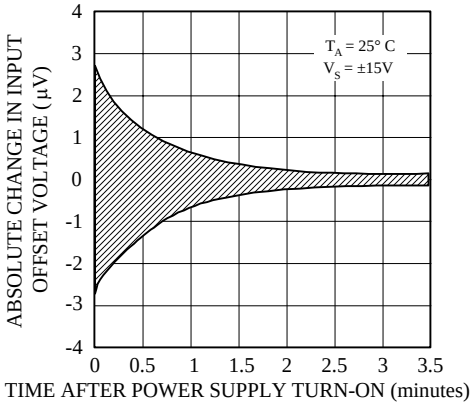
Note 5: Guaranteed by end-point limits.

TYPICAL PERFORMANCE CHARACTERISTICS

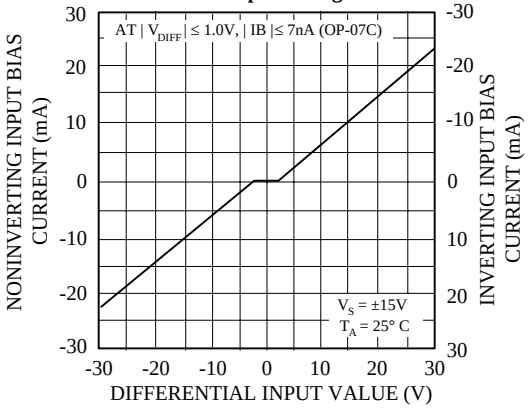
Open-Loop Gain vs Temperature



Warm-UpDrift

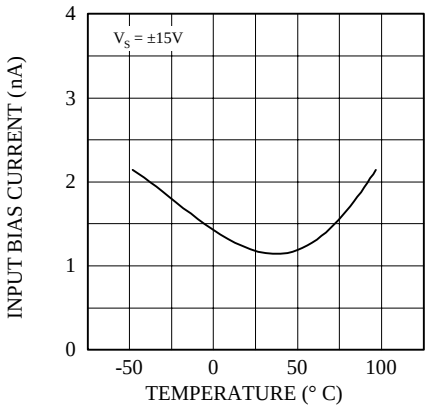


Input Bias Current vs Differential Input Voltage

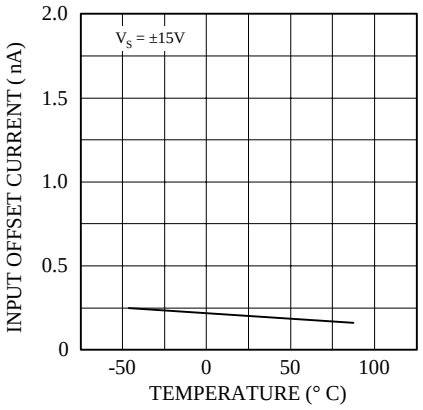


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

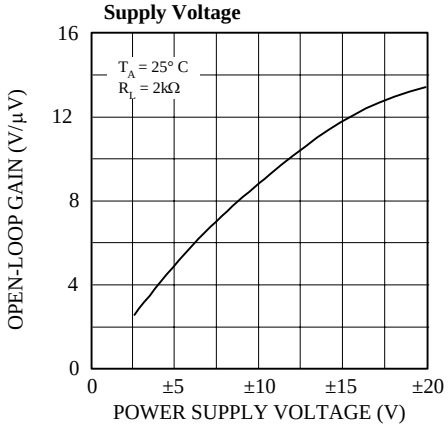
Input Bias Current vs Temperature



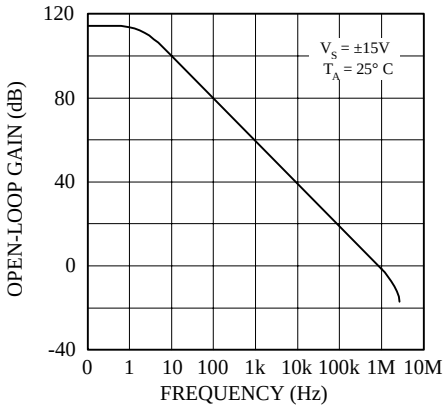
Input Offset Current vs Temperature



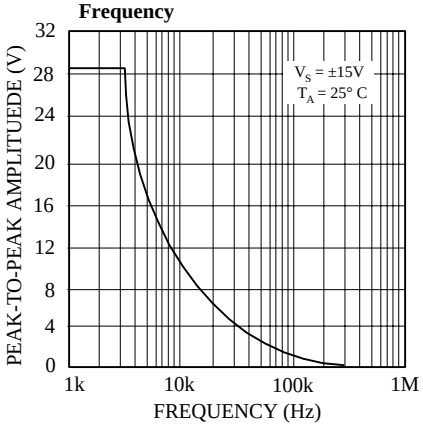
Open-Loop Gain vs Power Supply Voltage



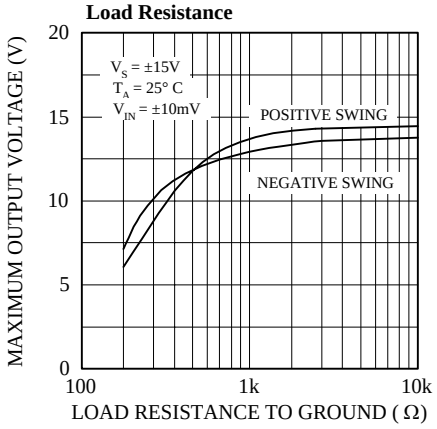
Open-Loop Frequency Response



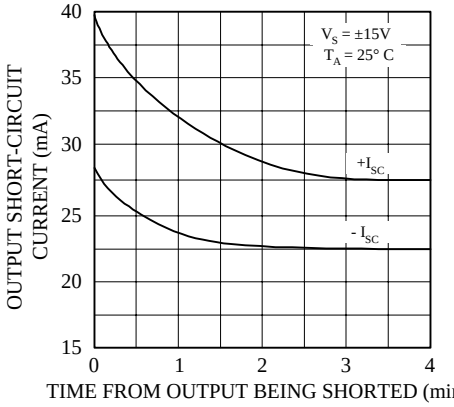
Maximum Output Swing vs Frequency



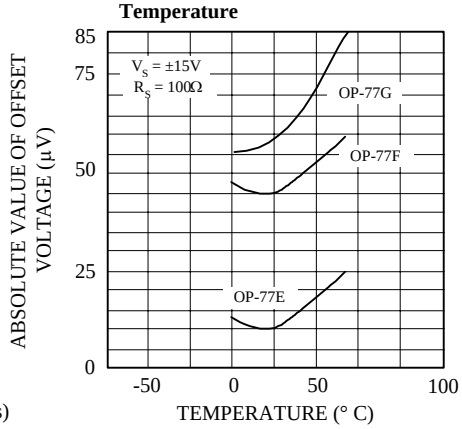
Maximum Output Voltage vs Load Resistance



Output Short-Circuit Current vs Time

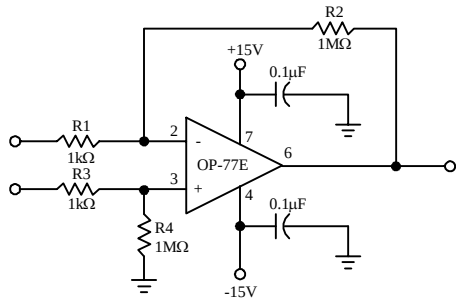


Untrimmed Offset Voltage vs Temperature



TYPICAL APPLICATIONS

Precision High-Gain Differential Amplifier



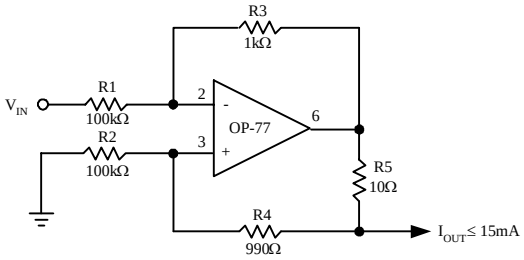
The high gain, gain linearity, CMRR, low TCV_{OS} of the OP-77 make it possible to obtain performance not previously available in single stage very high-gain amplifier applications.

For the best CMR, $\frac{R1}{R2}$ must equal $\frac{R3}{R4}$. In this example, with a 10mV differential signal, the maximum errors are as listed.

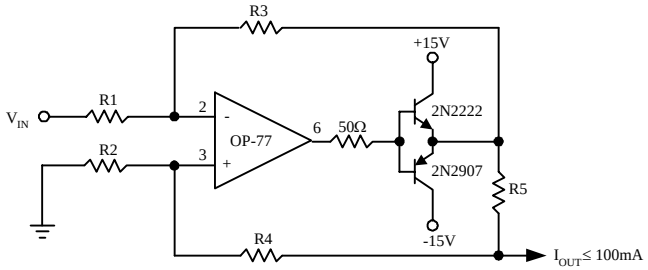
TYPE	AMOUNT
COMMON-MODE VOLTAGE	0.01%/V
GAIN LINEARITY, WORST CASE	0.02%
TCV_{OS}	0.008%/°C
TCI_{OS}	0.008%/°C

Bilateral Current Source

Basic Current Source



100mA current Source



$I_{OUT} = V_{IN}\frac{R3}{R1 * R5}$

GIVEN R3= R4+R5, R1=R2

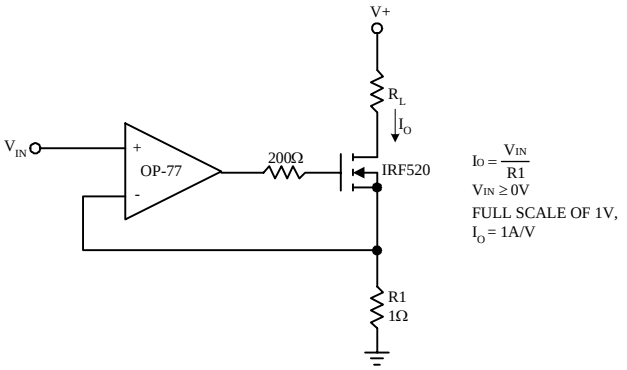
These current sources will supply both positive and negative current into a grounded load.

Note that $Z_O = \frac{R5\left(\frac{R4}{R2}+1\right)}{\frac{R5+R4}{R2}-\frac{R3}{R1}}$ and that for Z_O to be indefinite, $\frac{R5+R4}{R2}$ must $= \frac{R3}{R1}$.

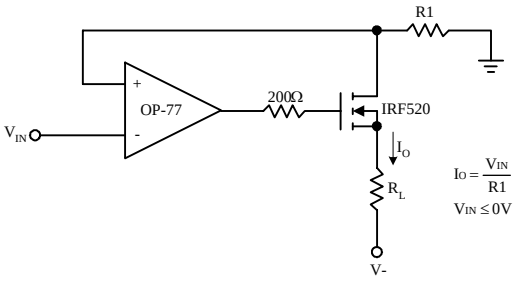
TYPICAL APPLICATIONS (Continued)

Precision Current Sinks

Positive Current Sink

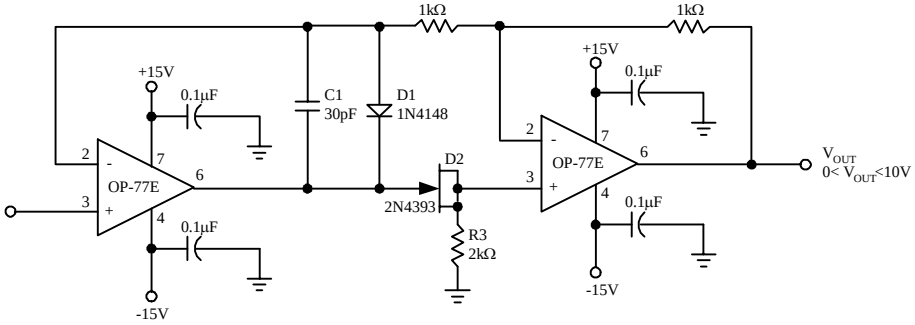


Positive current Source



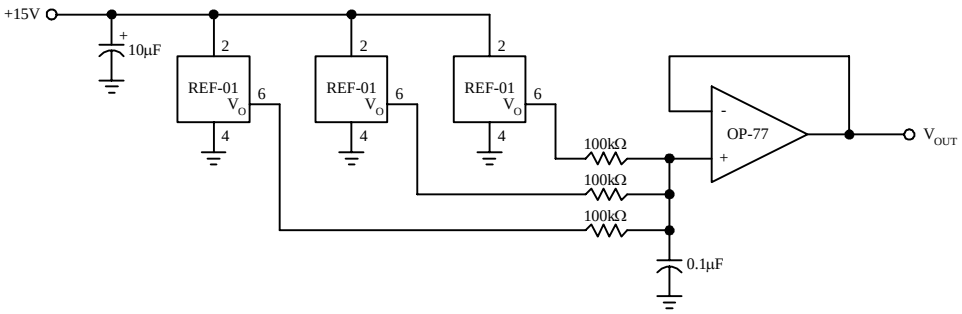
These simple high current sinks require that the load float between the power supply and the sink. In these circuits, OP-77's high gain, high CMRR, and low TCV_{OS} assure high accuracy.

Precision Absolute Value Amplifier



The high gain and low TCVOS assure accurate operation with inputs from microvolts to volts. In this circuit, this signal always appears as a common-mode signal to the op amps. The OP-77E CMRR of 1µV/V assures errors of less than 2ppm.

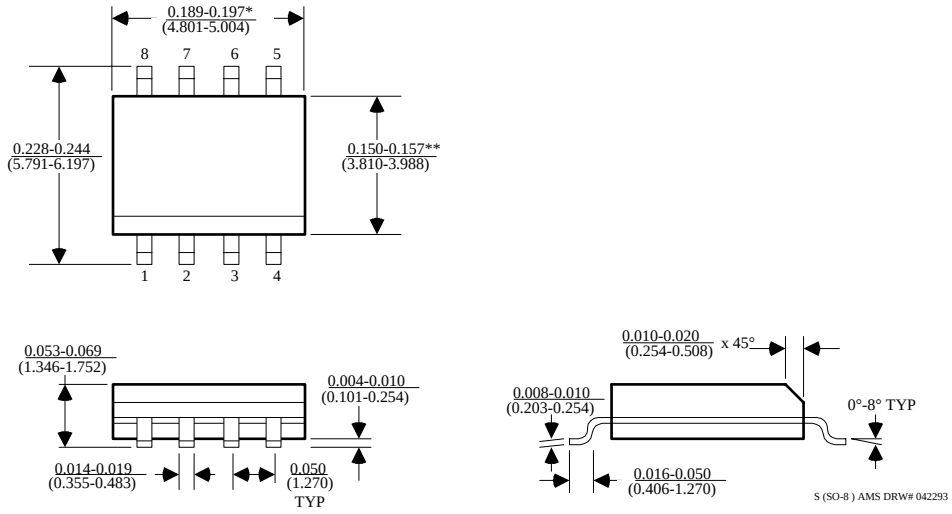
Low Noise Precision Reference



This circuit relies upon OP-77's low TCV_{OS} and noise combined with very high CMRR, to provide precision buffering of the averaged REF-01 voltage outputs.

PACKAGE DIMENSIONS inches (millimeters) unless otherwise noted.

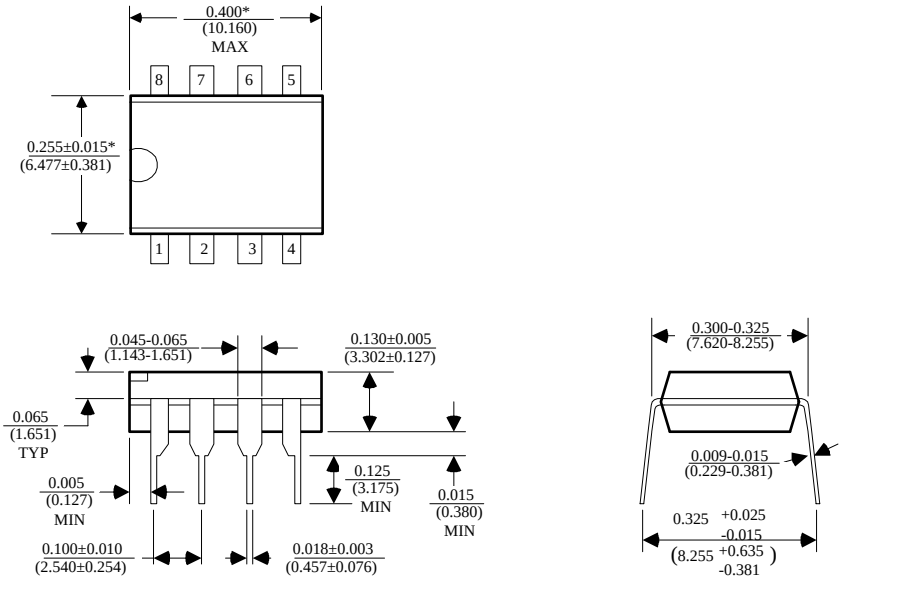
8 LEAD SOIC PLASTIC PACKAGE (S)



*DIMENSION DOES NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE

**DIMENSION DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE

8 LEAD PLASTIC DIP PACKAGE (P)



*DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTUSIONS. MOLD FLASH OR PROTUSIONS SHALL NOT EXCEED 0.010" (0.254mm)